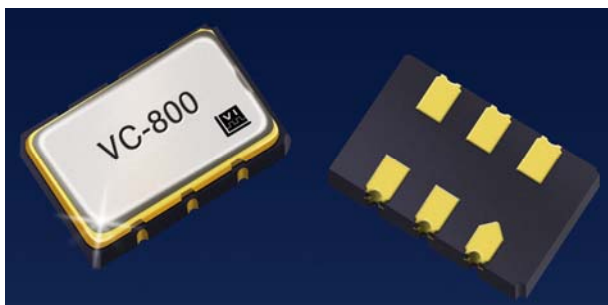


# VC-800

## Voltage Controlled Crystal Oscillator



The VC-800 Voltage Controlled Crystal Oscillator

### Features

- **Worlds Smallest VCXO, 5.0 X 3.2 X 1.5 mm**
- High Frequencies to 74.250 MHz
- 5.0 or 3.3 V operation
- Linearity  $\leq 10\%$
- Tri-State Output
- Low jitter < 6ps rms
- VCXO with CMOS outputs
- 0/70 or  $-40/85$  °C temperature range
- Hermetically sealed ceramic SMD package

Product is compliant to RoHS directive  and fully compatible with lead free assembly

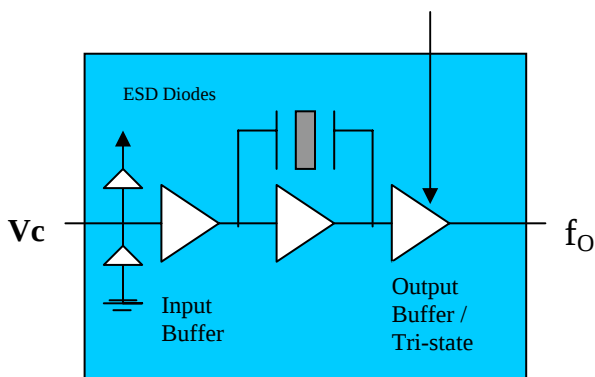
### Applications

- SONET/SDH
- DWDM
- xDSL/PCMCIA cards
- Digital Video

### Description

Vectron's VC-800 Voltage Controlled Crystal Oscillator (VCXO) is a quartz stabilized square wave generator with a CMOS output and is tested at CMOS and TTL (5.0 volt operation) logic levels.

The VC-800 is the smallest available VCXO making it ideally suitable for PCMCIA applications as well as any other where size is limited but performance is required.



# VC-800 Voltage Controlled Crystal Oscillator

## Performance Characteristics

| Table 1. Electrical Performance                                                                                 |                      |                                  |                                            |              |                                                          |
|-----------------------------------------------------------------------------------------------------------------|----------------------|----------------------------------|--------------------------------------------|--------------|----------------------------------------------------------|
| Parameter                                                                                                       | Symbol               | Min                              | Typical                                    | Maximum      | Units                                                    |
| Frequency                                                                                                       | $f_O$                | 1.544                            |                                            | 75.000       | MHz                                                      |
| Supply Voltage <sup>1</sup><br>(+3.3 V)<br>(+5.0 V)                                                             | $V_{DD}$             | 2.97<br>4.5                      | 3.3<br>5.0                                 | 3.63<br>5.5  | V                                                        |
| Supply Current                                                                                                  | $I_{DD}$             |                                  | 12                                         | 25           | mA                                                       |
| Output Logic Levels<br>Output Logic High <sup>2</sup><br>Output Logic Low <sup>2</sup>                          | $V_{OH}$<br>$V_{OL}$ | $0.9 \cdot V_{DD}$               |                                            | $0.1 V_{DD}$ | V<br>V                                                   |
| Transition Times<br>Rise Time <sup>2</sup><br>Fall Time <sup>2</sup>                                            | $t_R$<br>$t_F$       |                                  | 1<br>1                                     | 3<br>3       | ns<br>ns                                                 |
| Tristate<br>Output Enabled<br>Output Disabled                                                                   | $V_{IN}$<br>$V_{IL}$ | 2.5                              |                                            | 0.7          | V<br>V                                                   |
| Symmetry or Duty Cycle <sup>3</sup><br>(ordering option)                                                        | SYM                  | 40                               | 50                                         | 60           | %                                                        |
| Operating temperature (ordering option)                                                                         |                      | 0/70 or -40/85                   |                                            |              | °C                                                       |
| Test Conditions for APR (+5V option)                                                                            | $V_C$                | 0.5                              |                                            | 4.5          | V                                                        |
| Test Conditions for APR (+3.3V option)                                                                          | $V_C$                | 0.3                              |                                            | 3.0          | V                                                        |
| Absolute Pull Range (ordering option)                                                                           | APR                  | $\pm 50$<br>$\pm 70$<br>$\pm 80$ |                                            |              | ppm                                                      |
| Gain Transfer (See Figure 3)                                                                                    |                      | Positive                         |                                            |              | ppm/V                                                    |
| Control Voltage Leakage Current                                                                                 | $I_{VCXO}$           |                                  |                                            | $\pm 1$      | uA                                                       |
| Control Voltage Bandwidth (-3dB)                                                                                | BW                   | 10                               |                                            |              | kHz                                                      |
| Phase Noise<br>10 Hz Offset<br>100 Hz Offset<br>1 KHz Offset<br>10 KHz Offset<br>100 KHz Offset<br>1 MHz Offset |                      |                                  | -58<br>-88<br>-118<br>-143<br>-151<br>-151 |              | dBc/Hz<br>dBc/Hz<br>dBc/Hz<br>dBc/Hz<br>dBc/Hz<br>dBc/Hz |
| Package Size                                                                                                    |                      | 5.0 x 3.2 x 1.5                  |                                            |              | mm                                                       |

1. A 0.01uF and a 0.1uF capacitor should be located as close to the supply as possible (to ground) is recommended.
2. Figure 1 defines these parameters. Figure 2 illustrates the equivalent five gate TTL load and operating conditions under which these parameters are tested and specified.
3. Symmetry is defined as (ON TIME/PERIOD with  $V_S = 1.4$  V for TTL and  $V_S = 2.5$  V for CMOS, 5 volt operation, and  $V_S = 1.65$  V for 3.3 Volt operation.

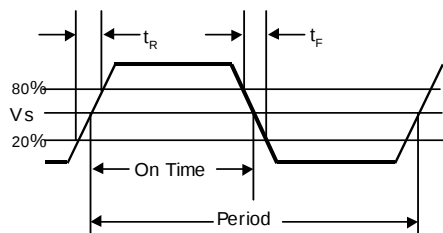


Figure 1. Output Waveform

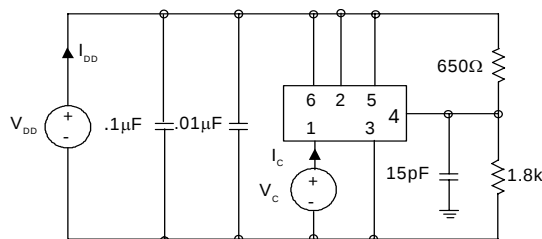
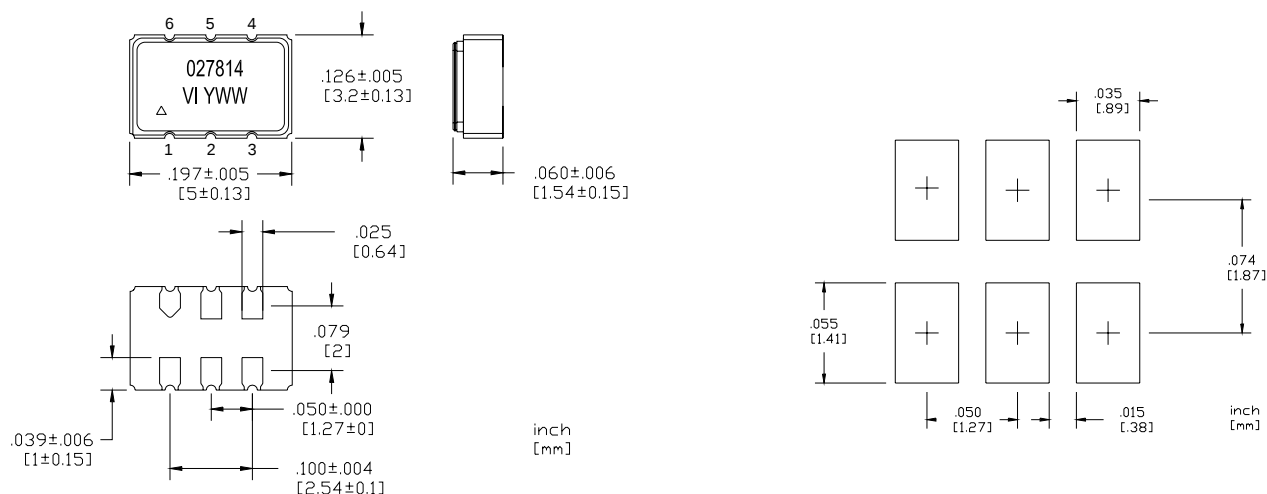


Figure 2. Typical Output Test Conditions (25±5°C)

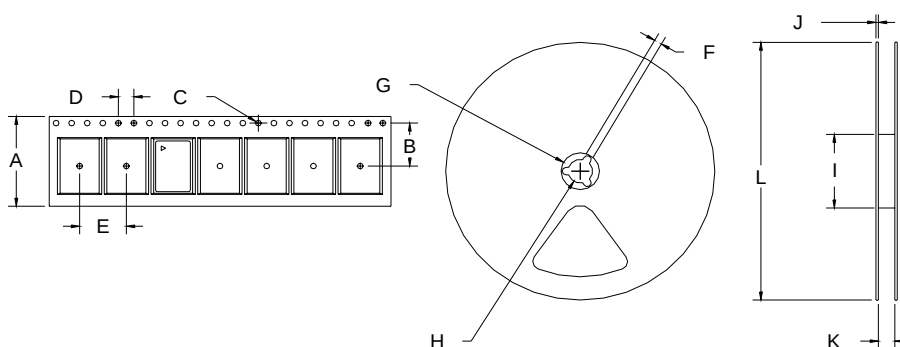
# VC-800 Voltage Controlled Crystal Oscillator

## Outline Diagram, Pad Layout and Pin Out



| Pin # | Symbol          | Function                                                                                        |
|-------|-----------------|-------------------------------------------------------------------------------------------------|
| 1     | V <sub>C</sub>  | Control Voltage                                                                                 |
| 2     | Tri-state       | Logic low disables output<br>Logic high or no connection enables output waveform                |
| 3     | GND             | Ground                                                                                          |
| 4     | f <sub>o</sub>  | Output Frequency                                                                                |
| 5     | CMOS/TTL        | Logic low for CMOS optimized symmetry<br>Logic high or no connection for TTL optimized symmetry |
| 6     | V <sub>DD</sub> | Supply Voltage                                                                                  |

## Tape and Reel



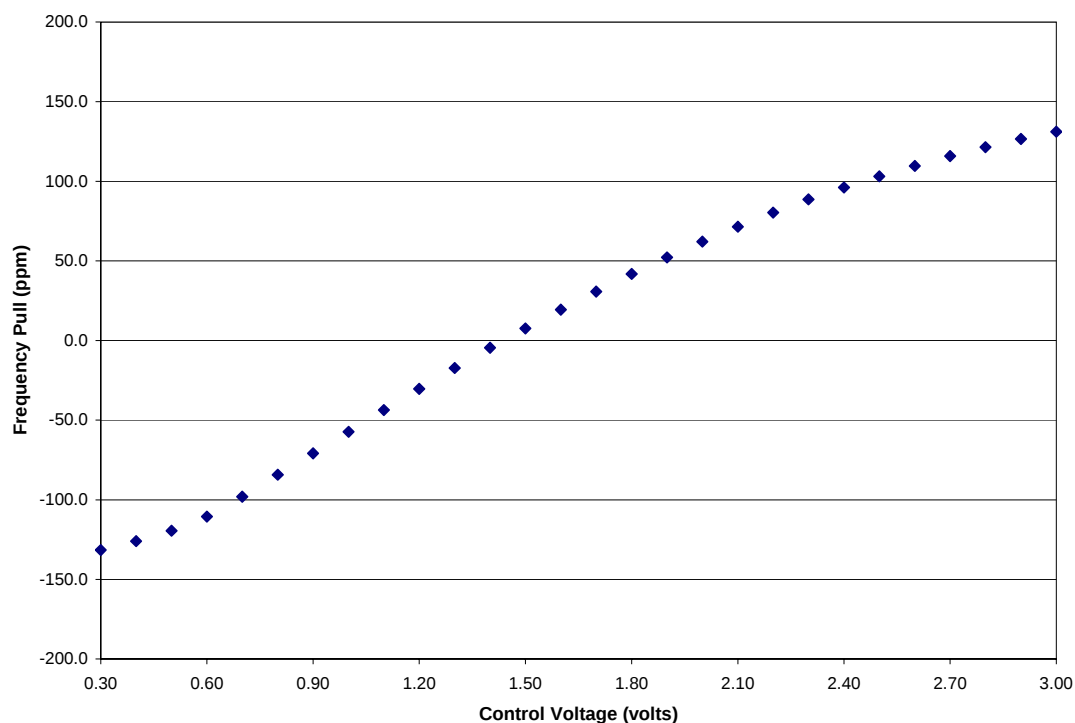
| Tape and Reel Dimensions (mm) |    |     |     |   |   |                 |      |    |    |   |      |     |            |
|-------------------------------|----|-----|-----|---|---|-----------------|------|----|----|---|------|-----|------------|
| Tape Dimensions               |    |     |     |   |   | Reel Dimensions |      |    |    |   |      |     | # Per Reel |
| Product                       | A  | B   | C   | D | E | F               | G    | H  | I  | J | K    | L   |            |
| VC-800                        | 12 | 5.5 | 1.5 | 4 | 8 | 1.78            | 20.6 | 13 | 55 | 6 | 12.4 | 178 | 500        |

## VC-800 Voltage Controlled Crystal Oscillator

### Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can permanently damage the device. Functional operation is not implied at these or any other conditions in excess of conditions represented in the operational sections of this data sheet. Exposure to absolute maximum ratings for extended periods may adversely affect device reliability.

| Table 2. Absolute Maximum Ratings |          |               |      |
|-----------------------------------|----------|---------------|------|
| Parameter                         | Symbol   | Ratings       | Unit |
| Power Supply                      | $V_{DD}$ | 6             | Vdc  |
| Storage Temperature               | Tstorage | -55/125       | °C   |
| Voltage Control Range             | $V_C$    | 0 to $V_{DD}$ | V    |



**Figure 3. Typical Frequency Pull Versus Control Voltage, 35.328MHz Output, 3.3 Volt Supply**

## VC-800 Voltage Controlled Crystal Oscillator

### Reliability

The VC-800 is capable of meeting the following qualification tests.

**Table 3. Environmental Compliance**

| Parameter              | Conditions              |
|------------------------|-------------------------|
| Mechanical Shock       | MIL-STD-883 Method 2002 |
| Mechanical Vibration   | MIL-STD-883 Method 2007 |
| Solderability          | MIL-STD-883 Method 2003 |
| Gross and Fine Leak    | MIL-STD-883 Method 1014 |
| Resistance to Solvents | MIL-STD-883 Method 2016 |

### Handling Precautions

Although ESD protection circuitry has been designed into the the VC-800, proper precautions should be taken when handling and mounting. VI employs a Human Body Model and a Charged-Device Model (CDM) for ESD susceptibility testing and design protection evaluation. ESD thresholds are dependent on the circuit parameters used to define the model. Although no industry wide standard has been adopted for the CDM, a standard HBM of resistance = 1.5kohms and capacitance = 100pF is widely used and therefore can be used for comparison purposes.

**Table 4. ESD Ratings**

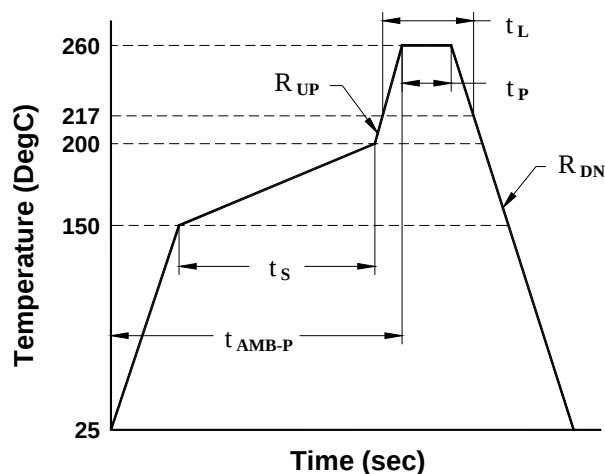
| Model                | Minimum | Conditions              |
|----------------------|---------|-------------------------|
| Human Body Model     | 1500    | MIL-STD-883 Method 3115 |
| Charged Device Model | 1000    | JESD 22-C101            |

The VC-800 is qualified to meet the JEDEC standard for Pb-Free assembly. The temperatures and time intervals listed are based on the Pb-Free small body requirements and parameters are listed in the table below. The contact pads are gold over nickel so lower IR reflow temperatures such as 220°C can be used (device is backwards compatible with a lead solder assembly).

The VC-800 is hermetically sealed so an aqueous wash is not an issue.

**Table 5. Reflow Profile (IPC/JEDEC J-STD-020C)**

| Parameter                | Symbol      | Value                   |
|--------------------------|-------------|-------------------------|
| PreHeat Time             | $t_s$       | 60 sec Min, 180 sec Max |
| Ramp Up                  | $R_{UP}$    | 3 °C/sec Max            |
| Time Above 217 °C        | $t_L$       | 60 sec Min, 150 sec Max |
| Time To Peak Temperature | $t_{AMB-P}$ | 480 sec Max             |
| Time At 260 °C           | $t_P$       | 20 sec Min, 40 sec Max  |
| Ramp Down                | $R_{DN}$    | 6 °C/sec Max            |



## VC-800 Voltage Controlled Crystal Oscillator

| Standard Frequencies (MHz) |        |        |        |        |
|----------------------------|--------|--------|--------|--------|
| 3.600                      | 4.096  | 8.192  | 10.000 | 12.960 |
| 13.500                     | 16.384 | 19.440 | 27.000 | 28.375 |
| 32.768                     | 34.560 | 38.785 | 44.736 | 51.840 |
| 74.1758                    | 74.250 |        |        |        |
|                            |        |        |        |        |
|                            |        |        |        |        |

Other frequencies may be available upon request

### Ordering Information

**VC - 800 - K A C - G T J - XX.XX**

**Product Family**

VC = VCXO

**Package**

800= 5.0x3.2x1.5 mm

**Input**

K = 5.0 Vdc  $\pm$  10%  
L = 3.3 Vdc  $\pm$  10%

**Output**

A = CMOS

**Frequency (MHz)**

**Symmetry**

J = 50 $\pm$ 5%  
K = 50 $\pm$ 10%

**Tristate**

T = Pin 2: Enable High (or Float) / Disable Low

**Absolute Pull Range**

G =  $\pm$  50 ppm minimum  
M =  $\pm$  70 ppm minimum  
N =  $\pm$  80 ppm minimum

**Operating Temperature**

C = 0°C to 70°C  
F = -40°C to 85°C

**NOTE: Not all combinations of options are available.**

### For Additional Information, Please Contact:



USA: Vectron International, 267 Lowell Rd, Hudson, NH 03051 . . . . .

Tel: 1-888-VECTRON-1

Fax: 1-888-FAX-VECTRON

EUROPE: . . . . .

Tel: 49 (0) 7268 8010

Fax: 49 (0) 7268 801281

ASIA: . . . . .

Tel: 86 21 5048 0777

Fax: 86 21 5048 1881

Vectron International reserves the right to make changes to the product(s) and/or information contained herein without notice.  
No liability is assumed as a result of their use or application. No rights under any patent accompany the sale of any such product(s) or information.